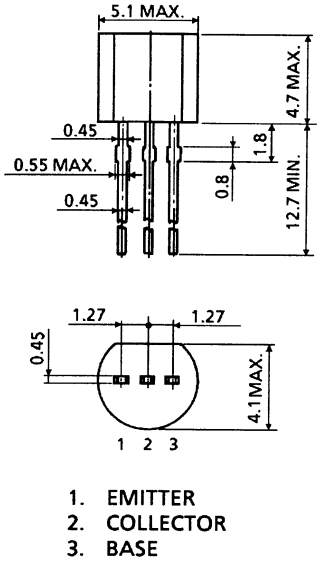
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT process)

2SC3112

For Audio Amplifier and Switching Applications

- High DC current gain: h_{FE} = 600~3600
- High breakdown voltage: V_{CEO} = 50 V
- High collector current: I_C = 150 mA (max)

Unit: mm



JEDEC	TO-92
JEITA	SC-43
TOSHIBA	2-5F1B

Weight: 0.21 g (typ.)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	50	V
Collector-emitter voltage	V_{CEO}	50	V
Emitter-base voltage	V_{EBO}	5	V
Collector current	I_C	150	mA
Base current	I_B	30	mA
Collector power dissipation	P_C	400	mW
Junction temperature	T_j	125	°C
Storage temperature range	T_{stg}	−55~125	°C

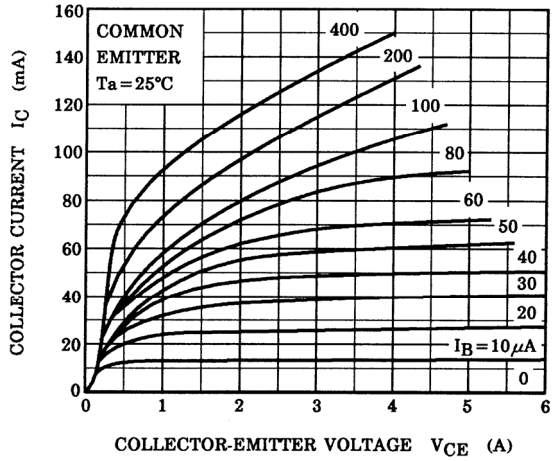
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Electrical Characteristics (Ta = 25°C)

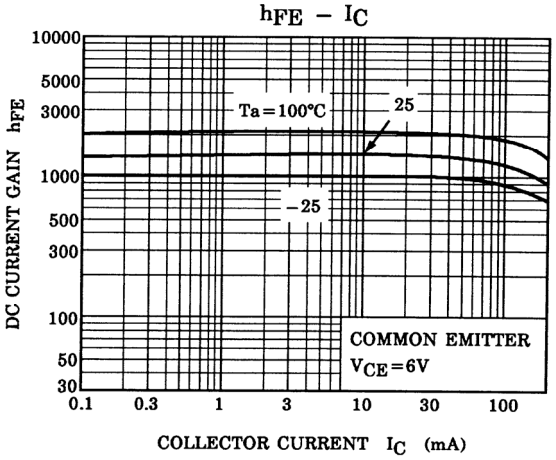
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	I_{CBO}	V_{CB} = 50 V, I_E = 0	—	—	0.1	μA
Emitter cut-off current	I_{EBO}	V_{EB} = 5 V, I_C = 0	—	—	0.1	μA
DC current gain	h_{FE} (Note)	V_{CE} = 6 V, I_C = 2 mA	600	—	3600	
Collector-emitter saturation voltage	$V_{CE\ (sat)}$	I_C = 100 mA, I_B = 10 mA	—	0.12	0.25	V
Transition frequency	f_T	V_{CE} = 10 V, I_C = 10 mA	100	250	—	MHz
Collector output capacitance	C_{ob}	V_{CB} = 10 V, I_E = 0, f = 1 MHz	—	3.5	—	pF
Noise figure	NF (1)	V_{CE} = 6 V, I_C = 0.1 mA, f = 100 Hz, R_G = 10 kΩ	—	0.5	—	dB
	NF (2)	V_{CE} = 6 V, I_C = 0.1 mA, f = 1 kHz, R_G = 10 kΩ	—	0.3	—	

Note: h_{FE} classification A: 600~1800, B: 1200~3600

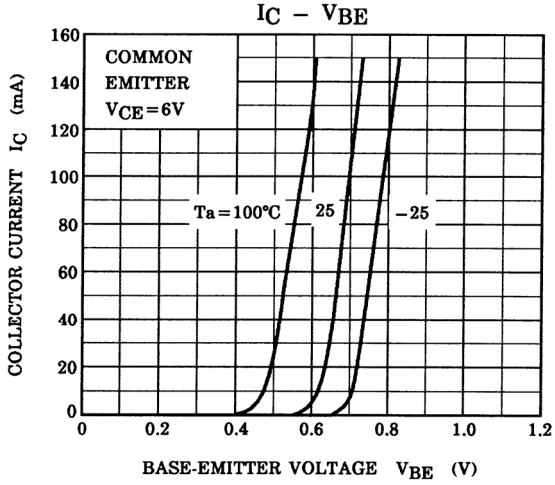
$I_C - V_{CE}$



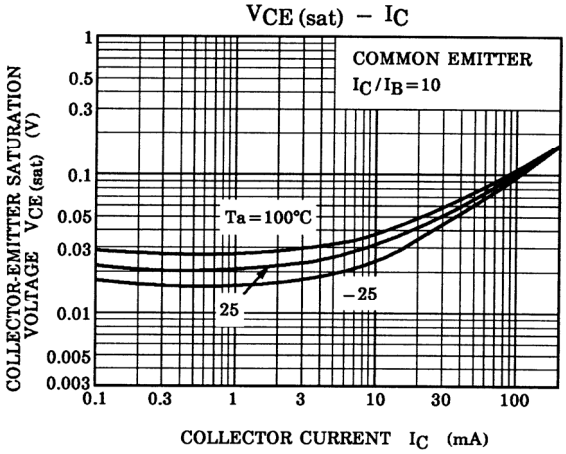
$h_{FE} - I_C$



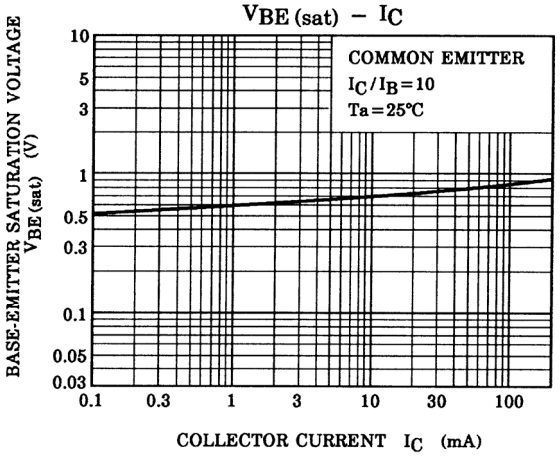
$I_C - V_{BE}$



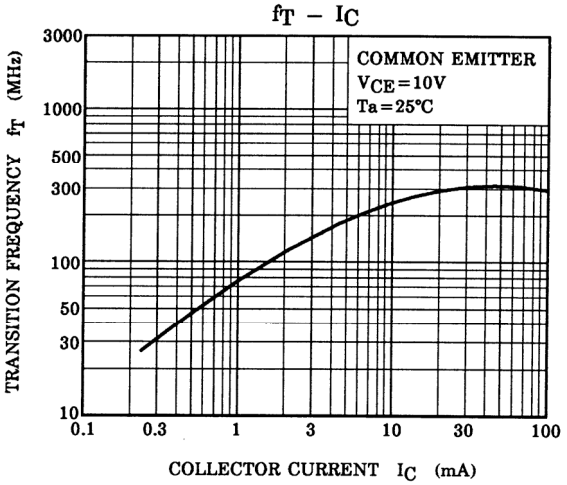
$V_{CE\,(sat)} - I_C$

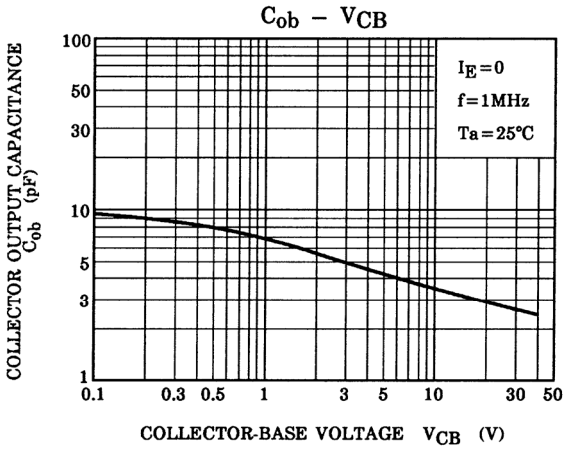


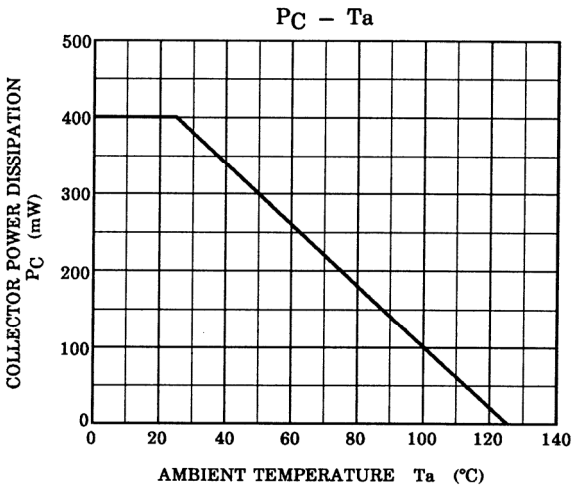
$V_{BE\,(sat)} - I_C$



$f_T - I_C$




C_{ob} – V_{CB}
COLLECTOR OUTPUT CAPACITANCE C_{ob} (pF)
100
50
30
10
5
3
1
0.1
0.3
0.5
1
3
5
10
30
50
I_E = 0
f = 1MHz
Ta = 25°C
COLLECTOR-BASE VOLTAGE V_{CB} (V)


P_C – Ta
COLLECTOR POWER DISSIPATION P_C (mW)
500
400
300
200
100
0
0
20
40
60
80
100
120
140
AMBIENT TEMPERATURE Ta (°C)

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20070701-EN GENERAL

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